



Gate Turn-off Thyristor

DS4090-5 July 2014 (LN31730)

FEATURES

- Double Side Cooling
- High Reliability In Service
- High Voltage Capability
- Fault Protection Without Fuses
- High Surge Current Capability
- Turn-off Capability Allows Reduction in Equipment Size and Weight. Low Noise Emission Reduces Acoustic Cladding Necessary For Environmental Requirements

APPLICATIONS

- Variable speed AC motor drive inverters (VSD-AC)
- Uninterruptable Power Supplies
- High Voltage Converters
- Choppers
- Welding
- Induction Heating
- DC/DC Converters

KEY PARAMETERS

V_{DRM}	2500V
$I_{T(AV)}$	500A
I _{TCM}	1200A
dV _D /dt	1000V/µs
dl _⊤ /dt	300A/μs

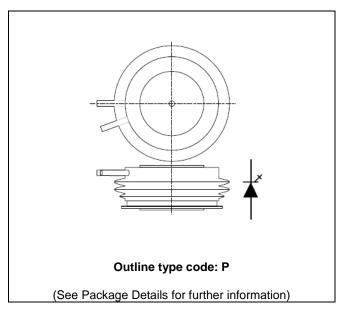


Fig. 1 Package outline

VOLTAGE RATINGS

Type Number	Repetitive Peak Off-state Voltage V _{DRM} (V)	Repetitive Peak Reverse Voltage V _{RRM} (V)	Conditions
DG406BP18	1800	16	T_{vj} = 125°C, I_{DM} =50mA, I_{RRM} = 50mA

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{TCM}	Repetitive peak controllable on-state current	$V_D = V_{DRM}, T_j = 125^{\circ}C,$ $dI_{GQ}/dt = 30A/\mu s, C_S = 1.5 \mu F$	1200	А
I _{T(AV)}	Mean on-state current	T _{HS} = 80°C, Double side cooled. Half sine 50Hz	500	Α
I _{T(RMS)}	RMS on-state current	T _{HS} = 80°C, Double side cooled. Half sine 50Hz	630	Α



SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{TSM}	Surge (non repetitive) on-state current	10ms half sine. T _j = 125°C	8.0	kA
l ² t	I ² t for fusing	10ms half sine. T _j = 125°C	0.32	MA ² s
di _⊤ /dt	Critical rate of rise of on-state current	$V_D = 1800V$, $I_T = 1000A$, $T_j = 125^{\circ}C$, $I_{FG} > 30A$, Rise time $> 1.0~\mu s$	300	A/μs
-1\/ /-1t	o/dt Rate of rise of off-state voltage	To 66% V_{DRM} ; $R_{GK} \le 1.5\Omega$, $T_j = 125^{\circ}C$	500	V/μs
dV _D /dt		To 66% V_{DRM} ; $V_{RG} \le -2V$, $T_j = 125$ °C	1000	V/μs
Ls	Peak stray inductance in snubber circuit	I_T = 1000A, V_{DM} = 1800V, T_j = 125°C, di_{GQ}/dt = 30A/ μ s, C_S = 1.0 μ F	200	nΗ

GATE RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V_{RGM}	Peak reverse gate voltage	This value may be exceeded during turn-off	-	16	V
I _{FGM}	Peak forward gate current		20	70	Α
P _{FG(AV)}	Average forward gate power		-	10	W
P_{RGM}	Peak reverse gate power		-	15	kW
di _{GQ} /dt	Rate of rise of reverse gate current		15	60	A/μs
t _{ON(min)}	Minimum permissible on time		20	-	μS
t _{OFF(min)}	Minimum permissible off time		100	-	μS

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-hs)} Thermal resistance – junction to heatsink surface	Thermal resistance – junction to	Double side cooled	DC	-	0.041	°C/W
	O	Anode DC	-	0.07	°C/W	
		Single side cooled	Cathode DC	-	0.1	°C/W
R _{th(c-hs)}	Contact thermal resistance	Clamping force 12.0kN With mounting compound	Per contact	-	0.009	°C/W
T _{vj}	Virtual junction temperature	On-state (conducting)		-	125	°C
T _{OP} /T _{stg}	Operating junction/storage temperature range			-40	125	°C
Fm	Clamping force			11.0	15.0	kN



CHARACTERISTICS

$T_j = 125$ °C unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Max.	Units
V_{TM}	On-state voltage	At 1000A peak, I _{G(ON)} = 4A dc	-	2.5	V
I _{DM}	Peak off-state current	$V_{DRM} = 1800V, V_{RG} = 0V$	1	50	mA
I _{RRM}	Peak reverse current	At V _{RRM}	-	50	mA
V_{GT}	Gate trigger voltage	$V_D = 24V$, $I_T = 100A$, $T_j = 25$ °C	-	1.0	V
I _{GT}	Gate trigger current	$V_D = 24V$, $I_T = 100A$, $T_j = 25$ °C	-	1.5	А
I _{RGM}	Reverse gate cathode current	V _{RGM} = 16V, No gate/cathode resistor	-	50	mA
Eon	Turn-on energy	V 4900V	-	1040	mJ
t _d	Delay time	$V_D = 1800V$ $I_T = 1000A$, $dI_T/dt = 300A/\mu s$ $I_{FG} = 30A$, rise time < 1.0 μs	-	1.5	μS
t _r	Rise time		-	3.0	μS
E _{OFF}	Turn-off energy		-	2300	mJ
t _{gs}	Storage time	1 1000 1	-	14.0	μS
t _{gf}	Fall time	$I_T = 1000A$,	-	1.5	μS
t _{gq}	Gate controlled turn-off time	$V_{DM}=2500V,$ Snubber capacitor $C_S=1.0\mu F,$ $di_{GQ}/dt=30A/\mu s$	-	15.5	μS
Q_{GQ}	Turn-off gate charge		-	3000	μС
Q_{GQT}	Total turn-off gate charge		-	6000	μС
I _{GQM}	Peak reverse gate current		-	420	А



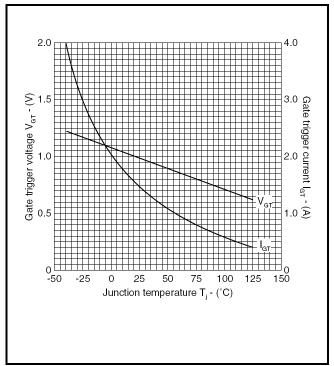


Fig.2 Maximum gate trigger voltage/current vs junction temperature

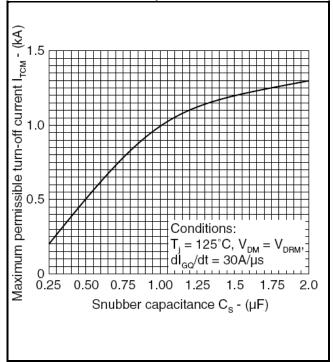


Fig.4 Maximum dependence of I_{TCM} on C_S

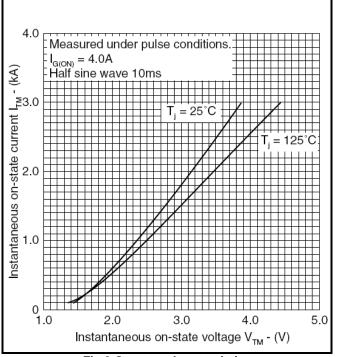


Fig.3 On-state characteristics

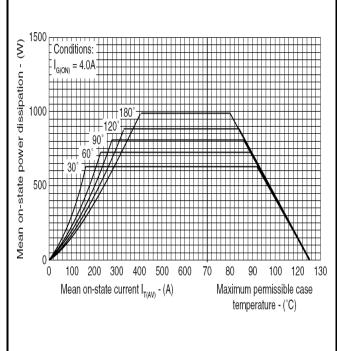
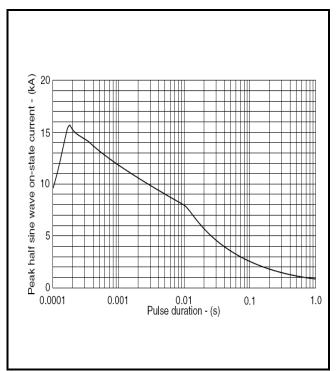


Fig.5 Steady state sinusoidal wave conduction loss – double side cooled





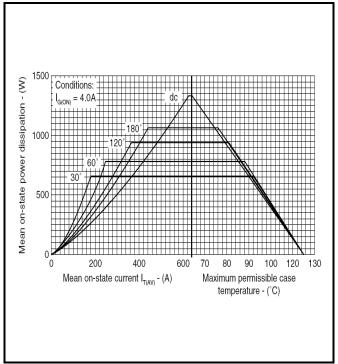


Fig.6 Surge (non-repetitive) on-state current vs time

Fig.7 Steady state rectangular wave conduction loss – double side cooled

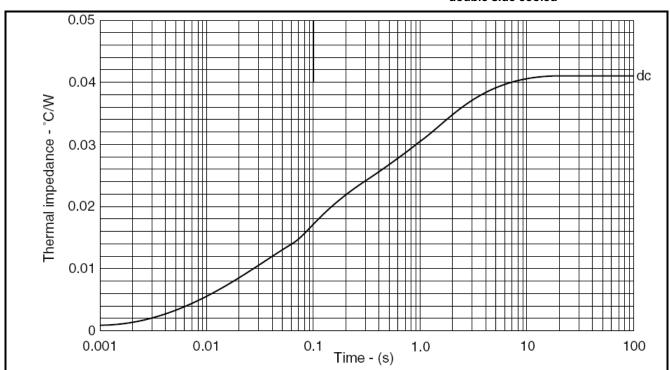


Fig.8 Maximum (limit) transient thermal impedance - junction to case (°C/kW)



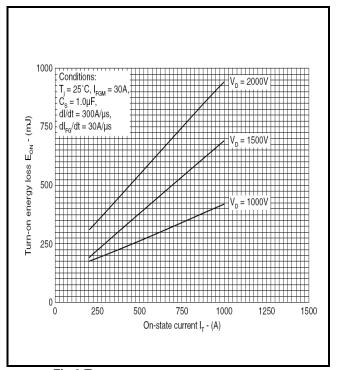


Fig.9 Turn-on energy vs on-state current

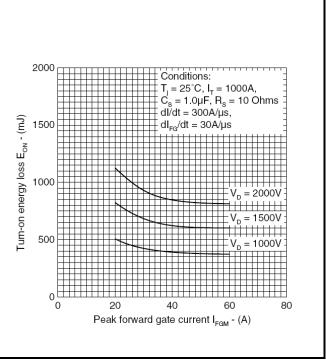


Fig.10 Turn-on energy vs peak forward gate current

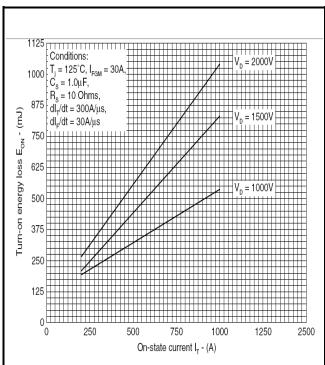


Fig.11 Turn-on energy vs on-state current

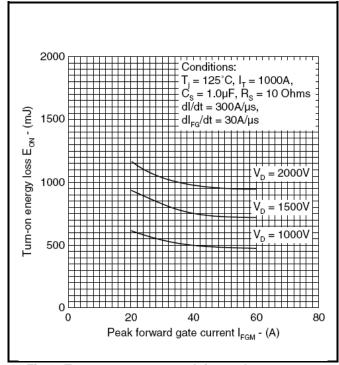
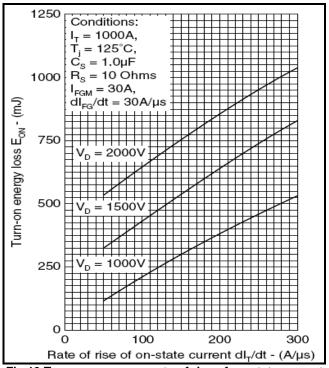
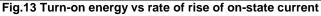


Fig.12 Turn-on energy vs peak forward gate current







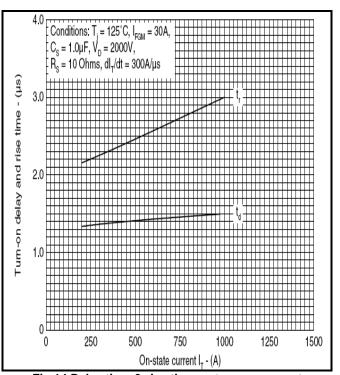


Fig.14 Delay time & rise time vs turn-on current

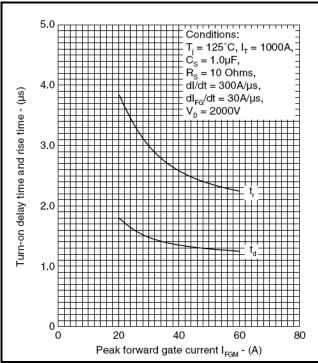


Fig.15 Delay time & rise time vs peak forward gate current

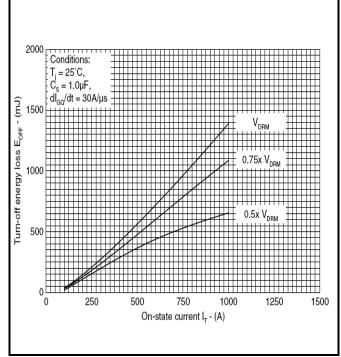


Fig.16 Turn-off energy vs on-state current



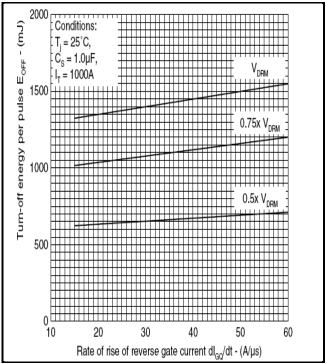


Fig.17 Turn-off energy vs rate of rise of reverse gate current

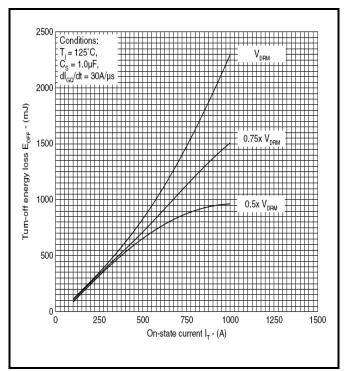


Fig.18 Turn-off energy vs on-state current

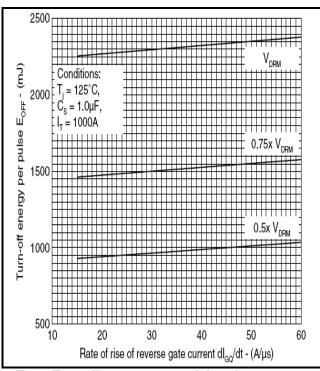


Fig.19 Turn-off energy vs rate of rise of reverse gate current

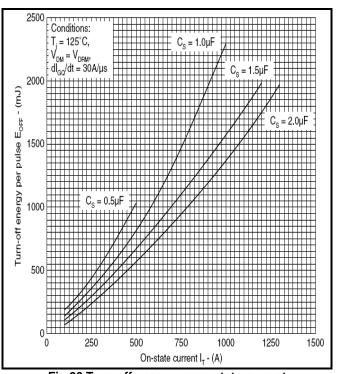


Fig.20 Turn-off energy vs on-state current



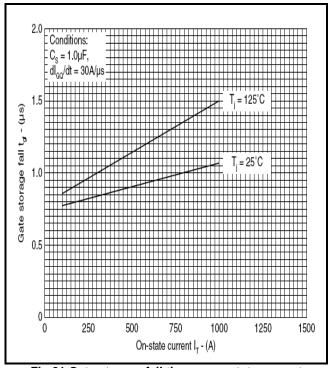


Fig.21 Gate storage fall time vs on-state current

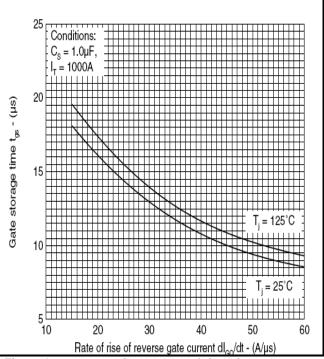


Fig.22 Gate storage time vs rate of rise of reverse gate current

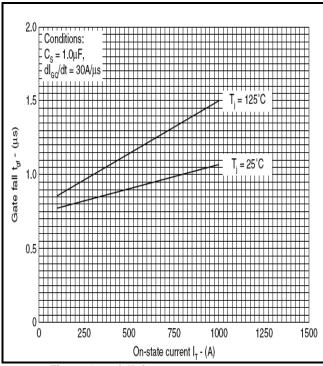


Fig.23 Gate fall time vs on-state current

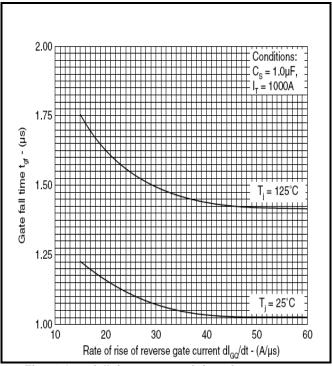


Fig.24 Gate fall time vs rate of rise of reverse gate current



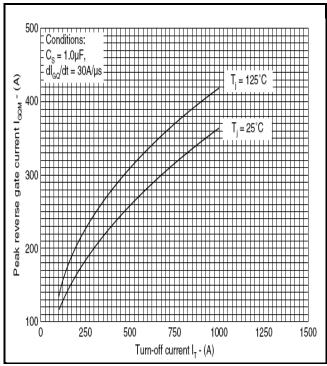


Fig.25 Peak reverse gate current vs turn-off current

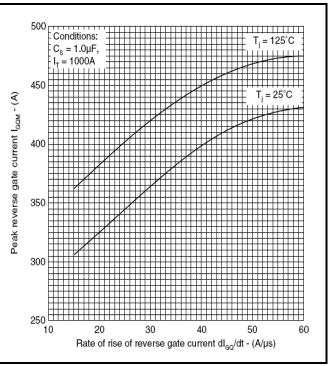


Fig.26 Peak reverse gate current vs rate of rise of reverse gate current

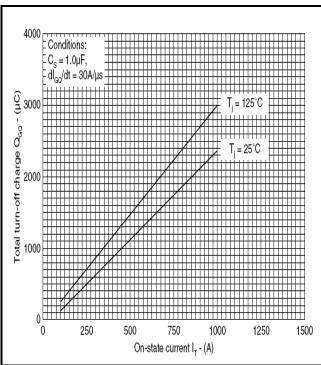


Fig.27 Turn-off gate charge vs on-state current

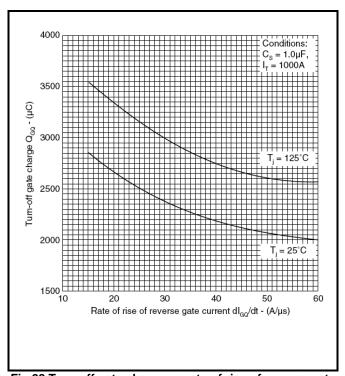


Fig.28 Turn-off gate charge vs rate of rise of reverse gate current



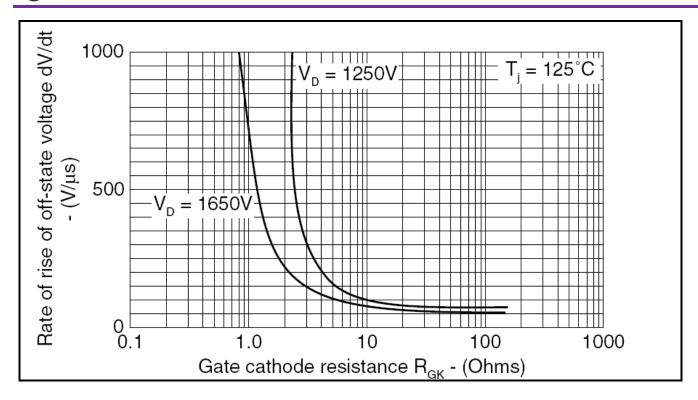


Fig.29 Rate of rise of off-state voltage vs gate cathode resistance



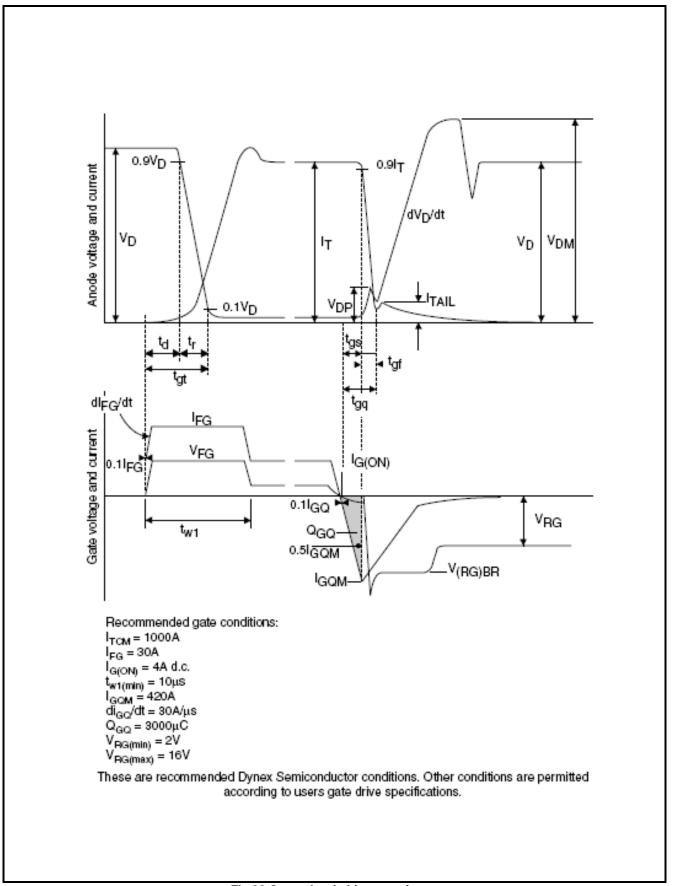


Fig.30 General switching waveforms



PACKAGE DETAILS

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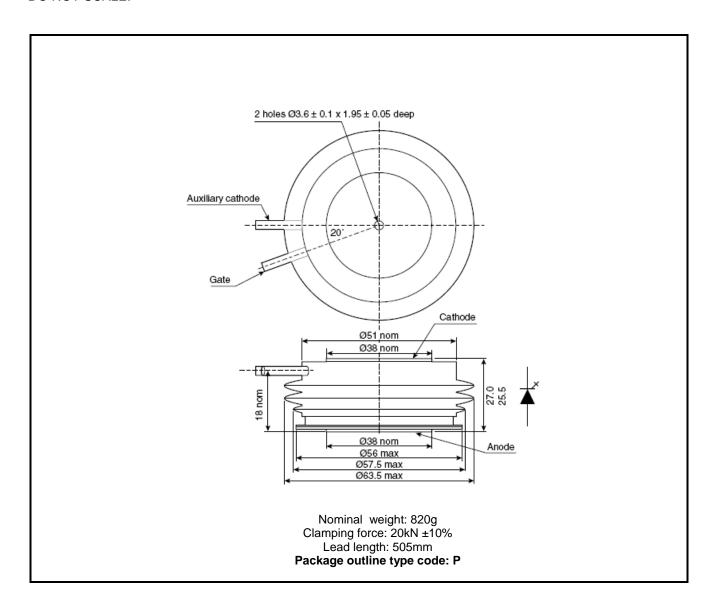


Fig.31 Package outline

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